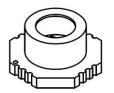
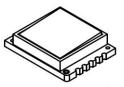


# IC03110-01, IC03120-01

# PRELIMINARY DATASHEET

# InAsSb room-temperature infrared detection modules with an integrated ASIC-type amplifier





TO39 cap

square-shaped cap

#### **FEATURES**

- Spectral range: 2.0 to 5.6 µm
- RoHS-compliant III-V material
- Front-side illuminated
- ASIC-type electronics
- Programmable gain
- DC coupling (AC coupling on request)
- Compact, surface-mount type package
- Long-term stability and reliability
- High ambient operating and storage temperature
- Low power consumption
- Possibility of mounting optical filters

#### **APPLICATIONS**

- Contactless temperature measurement: railway transport, industrial and laboratory processes monitoring
- Flame and explosion detection
- Threat warning systems
- Heat-seeking, thermal signature detection
- Dentistry
- Gas detection, monitoring and analysis:  $CH_4$ ,  $C_2H_2$ ,  $CH_2O$ , HCI,  $NH_3$ ,  $SO_2$ ,  $C_2H_6$ , CO,  $CO_2$ ,  $NO_x$
- Breath analysis: C<sub>2</sub>H<sub>6</sub>, CH<sub>2</sub>O, NH<sub>3</sub>, NO, OCS
- Gas leak detection
- Combustion process control
- · Non-destructive material testing

#### **DETECTION MODULE CONFIGURATION**

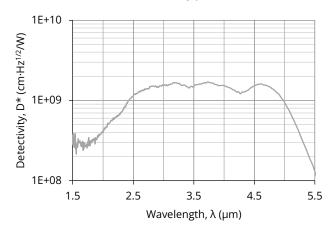
Detection module symbol	Cooling	Temperature sensor	Active area diamater, d <sub>A</sub> , mm	Optical immersion	Format	Acceptance angle Ф, deg.	Window
IC03110-01	no	n/a	1	no	TO39 cap	~70	wZnSeAR (3 deg. wedged sinc selenide, anti- reflection coating)
IC03120-01					square-shaped cap	>14()	

#### SPECIFICATION ( $T_{amb} = 293 \text{ K}$ , $R_{load} = 50 \Omega$ )

Parameter	Test conditions, remarks	Value			Linit
Parameter	rest conditions, remarks	Min.	Тур.	Max.	Unit
Active element temperature, T <sub>chip</sub>	$T_{chip} = T_{amb}$	-	293	-	K
Cut-on wavelength, λ <sub>cut-off</sub> (10%)	At 10% of peak responsivity	-	≤2.0	-	μm
Peak wavelength, λ <sub>peak</sub>		-	4.5	-	μm
Cut-off wavelength, λ <sub>cut-off</sub> (10%)	At 10% of peak responsivity	-	5.6	-	μm
Detectivity, D*	At $\lambda_{peak}$ , f = 10 kHz	-	1.7×10 <sup>9</sup>	-	cm·Hz <sup>1/2</sup> /W
Output noise voltage density, v <sub>n</sub>	At f = 10 kHz	-	1.4	-	μV/Hz <sup>1/2</sup>
Voltage responsivity, R <sub>v</sub>	At $\lambda = \lambda_{peak}$	-	2.8×10 <sup>4</sup>	-	V/W
Transimpedance, K <sub>i</sub>		16	-	640	kV/A
Low cut-off frequency, f <sub>lo</sub>	DC coupling	-	0	-	Hz
High cut-off frequency, f <sub>hi</sub>		-	5	-	MHz
Output impedance, R <sub>out</sub>		-	50	-	Ω
Reference voltage output, V <sub>ref</sub>		-	1	-	V
Power supply voltage, +V <sub>sup</sub>		-	3.3	-	V
Power consumption, P		-	0.15	-	W



# SPECTRAL RESPONSE (Typ., T<sub>amb</sub> = 293 K)



### MECHANICAL LAYOUT AND SIGNAL OUTPUT

- IC03110-01 detection module technical drawing
- IC03120-01 detection module technical drawing

#### ABSOLUTE MAXIMUM RATINGS

Parameter	Test conditions, remarks	Value	Unit
Ambient operating temperature, T <sub>amb</sub>	Detection module parameters depend on T <sub>amb</sub>	-20 to 70	°C
Storage temperature, T <sub>stg</sub>		-20 to 70	°C
Storage humidity	No dew condensation	10 to 90	%

Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. Constant or repeated exposure to absolute maximum rating conditions may affect the quality and reliability of the device.